

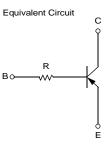
KSR2011

Switching Application (Bias Resistor Built In)

- Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor (R=22KΩ)
- Complement to KSR1011







PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

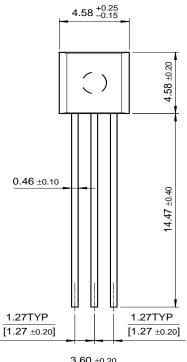
| Symbol | Parameter | Value | Units |
|------------------|-----------------------------|-----------|-------|
| V _{CBO} | Collector-Base Voltage | -40 | V |
| V_{CEO} | Collector-Emitter Voltage | -40 | V |
| V _{EBO} | Emitter-Base Voltage | -5 | V |
| I _C | Collector Current | -100 | mA |
| P _C | Collector Power Dissipation | 300 | mW |
| T _J | Junction Temperature | 150 | °C |
| T _{STG} | Storage Temperature | -55 ~ 150 | °C |

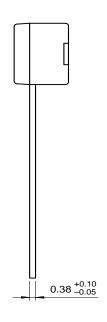
Electrical Characteristics T_a =25°C unless otherwise noted

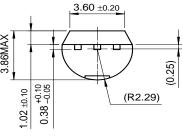
| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
|-----------------------|--------------------------------------|---|------|------|------|-------|
| BV _{CBO} | Collector-Base Breakdown Voltage | $I_C = -100 \mu A, I_E = 0$ | -40 | | | V |
| BV _{CEO} | Collector-Emitter Breakdown Voltage | I_E = -1mA, I_B =0 | -40 | | | V |
| I _{CBO} | Collector Cut-off Current | V_{CB} = -30V, I_{E} =0 | | | -0.1 | μΑ |
| h _{FE} | DC Current Gain | V_{CE} = -5V, I_{C} = -1mA | 100 | | 600 | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I _C = -10mA, I _B = -1mA | | | -0.3 | V |
| C _{ob} | Output Capacitance | V_{CB} = -10V, I_{E} =0 f=1MHz | | 5.5 | | pF |
| f _T | Current Gain Bandwidth Product | V_{CE} = -10V, I_{C} = -5mA | | 200 | | MHz |
| R | Input Resistor | | 15 | 22 | 29 | ΚΩ |

Package Demensions

TO-92







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